# NSN 5961-00-163-0140

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Inclosure Material:

Metal

**Overall Length:** 

0.450 inches

# **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

# Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Anode

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

400.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current

# Power Rating Per Characteristic:

75.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 tab, solder lug and 1 case

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

No

# Fiig:

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